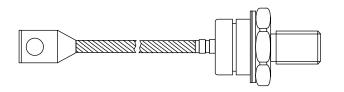


## Vishay High Power Products

# Standard Recovery Diodes (Stud Version), 200 A



### DO-205AC (DO-30)

### **FEATURES**

- Wide current range
- High voltage ratings up to 2400 V
- High surge current capabilities
- · Stud cathode and stud anode version
- Standard JEDEC types
- · Compression bonded encapsulations
- · RoHS complaint
- Lead (Pb)-free
- Designed and qualified for industrial level

PRODUCT SUMMARY				
I <sub>F(AV)</sub>	200 A			

### **TYPICAL APPLICATIONS**

- Converters
- · Power supplies
- · Machine tool controls
- · High power drives
- · Medium traction applications

MAJOR RATIN	MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	SD200	N/R	LINUTO	
PARAMETER	TEST CONDITIONS	1600 to 2000	2400	UNITS	
		200		Α	
I <sub>F(AV)</sub>	T <sub>C</sub>	110		°C	
I <sub>F(RMS)</sub>		314			
1	50 Hz	4700		A	
I <sub>FSM</sub>	60 Hz	4920			
2t	50 Hz	110		1.42-	
1-1	60 Hz	101		kA <sup>2</sup> s	
V <sub>RRM</sub>	Range	1600 to 2000	2400	V	
T <sub>J</sub>		- 40 to 180	150	°C	

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA	
	16	1600	1700		
SD200N/R	20	2000	2100	15	
	24	2400	2500		

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## SD200N/R Series



## Vishay High Power Products Standard Recovery Diodes (Stud Version), 200 A

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current				200	Α	
at case temperature		1000 can deather half size ways	1000		110	°C
Maximum average forward current	I <sub>F(AV)</sub>	160 CONG	duction, half sine wave 220	220	А	
at case temperature					100	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 95 °	C case tempera	ature	314	
		t = 10 ms	No voltage		4700	
Maximum peak, one-cycle forward,		t = 8.3  ms	reapplied		4920	Α
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		3950	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	4140	
	l <sup>2</sup> t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	110	kA <sup>2</sup> s
Maximum 12t for fusing		t = 8.3 ms	reapplied		101	
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		78	
		t = 8.3 ms	reapplied		71	
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 to 1	t = 0.1 to 10 ms, no voltage reapplied		1100	kA²√s
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.90	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		1.00		
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x I <sub>F(AV)</sub> < I < $\pi$ x I <sub>F(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum		0.79	mC.	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.64	- mΩ	
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 630 \text{ A}, T_J = T_J \text{ maximum},$ $t_p = 10 \text{ ms sinusoidal wave}$		1.40	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	ER SYMBOL TEST CONDITIONS	TEST COMPLIANCE	SD200	UNITS	
PANAMETEN		1600 to 2000	2400	UNITS	
Maximum junction operating temperature range	TJ		- 40 to 180	- 40 to 150	°C
Maximum storage temperature range	T <sub>Stg</sub>	- 55 to 200		200	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation 0.23		3	K/W
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	g surface, smooth, flat and greased 0.08		IV/VV
Maximum allowed mounting torque ± 10 %		Not-lubricated threads 14		ļ	Nm
Approximate weight			120	0	g
Case style		See dimensions (link at the end of datasheet)	DO-2	05AC (DO-30)	



## Standard Recovery Diodes Vishay High Power Products (Stud Version), 200 A

△R <sub>thJC</sub> CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.041	0.030			
120°	0.049	0.051			
90°	0.063	0.068	$T_J = T_J$ maximum	K/W	
60°	0.093	0.096			
30°	0.156	0.157			

#### Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

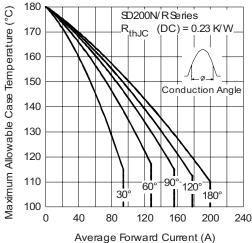


Fig. 1 - Current Ratings Characteristics

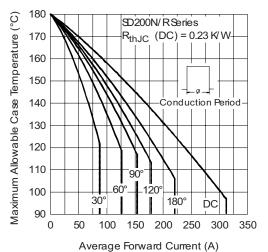
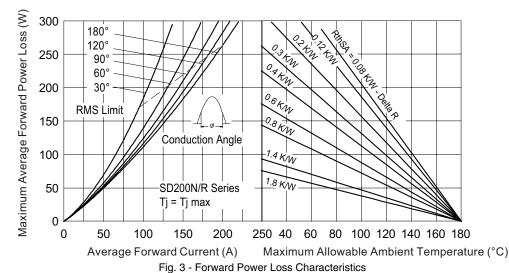


Fig. 2 - Current Ratings Characteristics



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## Vishay High Power Products Standard Recovery Diodes (Stud Version), 200 A



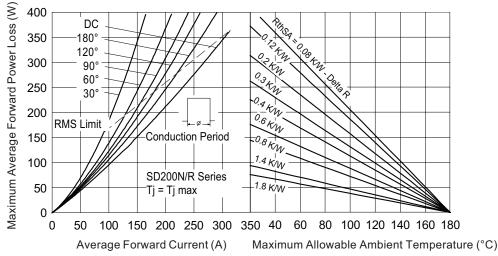
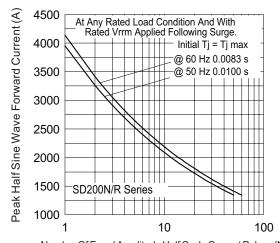
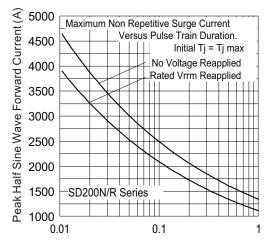


Fig. 4 - Forward Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current



Pulse Train Duration (s) Fig. 6 - Maximum Non-Repetitive Surge Current

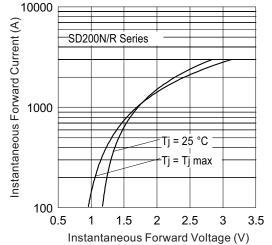


Fig. 7 - Forward Voltage Drop Characteristics

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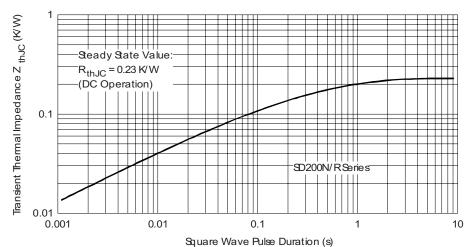
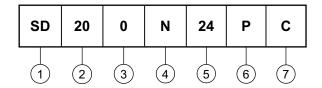


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristic

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Diode
- 2 Essential part number
- 3 0 = Standard recovery
- 4 • N = Stud normal polarity (cathode to stud)
  - R = Stud reverse polarity (anode to stud)
- 5 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- 6 • P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A
  - M = Stud base DO-205AC (DO-30) M12 x 1.75
- 7 C = Ceramic housing

For metric device M12 x 1.75 contact factory

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95302				

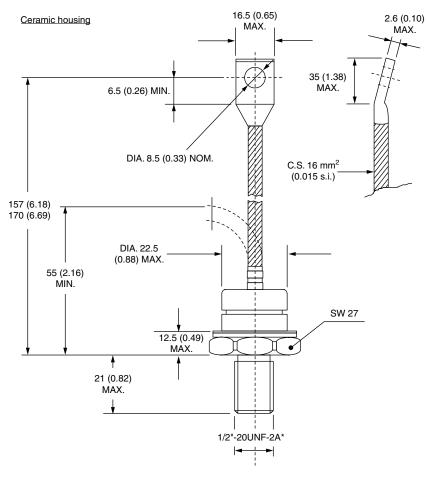
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## Vishay Semiconductors

## DO-205AC (DO-30)

### **DIMENSIONS** in millimeters (inches)



\*For metric device: M12 x 1.75 contact factory



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